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FDS8984 N-Channel PowerTrench[®] MOSFET 30V, 7A, 23mΩ

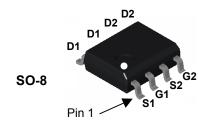
General Description

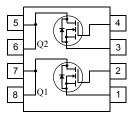
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{\rm DS(ON)}$ and fast switching speed.



Features

- Max r_{DS(on)} = 23mΩ, V_{GS} = 10V, I_D = 7A
- Max r_{DS(on)} = 30mΩ, V_{GS} = 4.5V, I_D = 6A
- Low gate charge
- 100% R_G tested
- RoHS Compliant





MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DS}	Drain to Source Voltage		30	V
V _{GS}	Gate to Source Voltage		±20	V
1	Drain Current Continuous	(Note 1a)	7	Α
I _D	Pulsed		30	Α
E _{AS}	Single Pulse Avalache Energy	(Note 2)	32	mJ
P _D	Power Dissipation for Single Operation		1.6	W
	Derate above 25°C		13	mW/°C
T _J , T _{STG}	Operating and Storage Temperature		-55 to 150	°C
Therma	Characteristics			
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	40	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS8984	FDS8984	SO-8	330mm	12mm	2500 units

$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	eristics Drain to Source Breakdown Voltage Breakdown Voltage Temperature Coefficient	$I_D = 250\mu A$, $V_{GS} = 0V$ $I_D = 250\mu A$, referenced to	30			
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature	$I_D = 250 \mu A$, referenced to	30			
$\frac{\Delta BV_{DSS}}{\Delta T_{J}} \qquad \qquad E$	o 1	$I_D = 250 \mu A$, referenced to				V
DSS Z		25°C		23		mV/°C
	Zero Gate Voltage Drain Current	$V_{DS} = 24V$ $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			1 250	μΑ
I _{GSS} (Gate to Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA
	eristics (Note 3)				0.5	
00(11)	Gate to Source Threshold Voltage	D3 63 [,] D		1.7	2.5	V
05(0)	Gate to Source Threshold Voltage	I _D = 250μA, referenced to 25°C		- 4.3		mV/°C
		V _{GS} = 10V, I _D = 7A		19	23	mΩ
		V _{GS} = 4.5V, I _D = 6A		24	30	
r _{DS(on)} L	Drain to Source On Resistance	$V_{GS} = 10V, I_D = 7A,$ T _J = 125°C		26	32	
D		0				
•	naracteristics					-
100	nput Capacitance	→ V _{DS} = 15V, V _{GS} = 0V, → f = 1.0MHz		475	635	pF
000	Dutput Capacitance			100	135	pF
133	Reverse Transfer Capacitance			65	100	pF
R _G (Sate Resistance	f = 1MHz		0.9	1.6	Ω
Switching C	Characteristics (Note 3)					
t _{d(on)} 1	urn-On Delay Time			5	10	ns
	Rise Time	V _{DD} = 15V, I _D = 7A		9	18	ns
	urn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 33\Omega$		42	68	ns
	all Time	-		21	34	ns
	otal Gate Charge	V _{DS} = 15V, V _{GS} = 10V, I _D = 7A		9.2	13	nC
Q _q 1	otal Gate Charge	V _{DS} = 15V, V _{GS} = 5V,		5.0	7	nC
0	Gate to Source Gate Charge	$I_D = 7A$		1.5		nC
3-	Gate to Drain "Miller" Charge			2.0		nC



mounted on a 0.5in⁴ pad of 2 oz copper

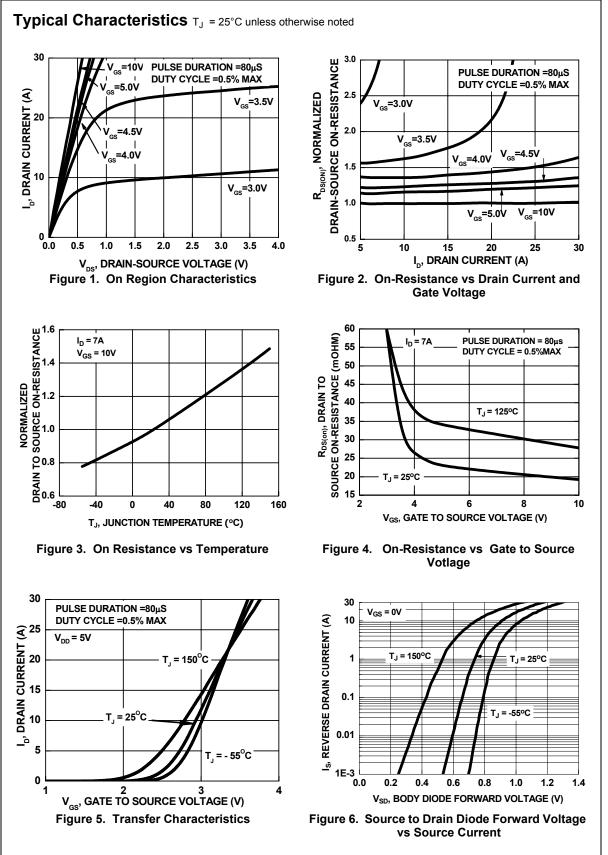
minimun pad

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Scale 1 : 1 on letter size paper

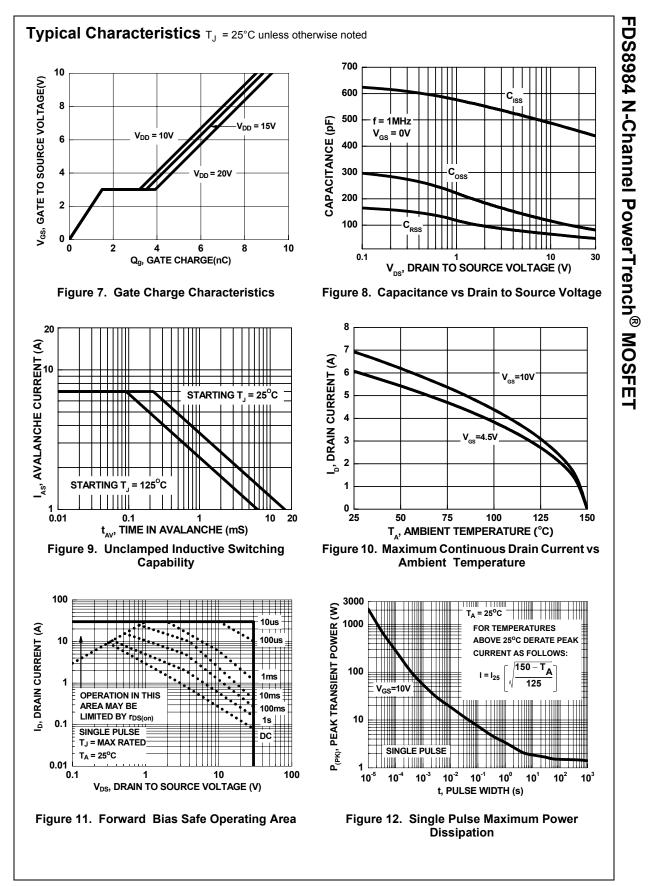
2: Starting  $T_J$  = 25°C, L = 1mH,  $I_{AS}$  = 8A,  $V_{DD}$  = 27V,  $V_{GS}$  = 10V. 3: Pulse Test:Pulse Width <300 $\mu$ S, Duty Cycle <2%.

pad of oz copper

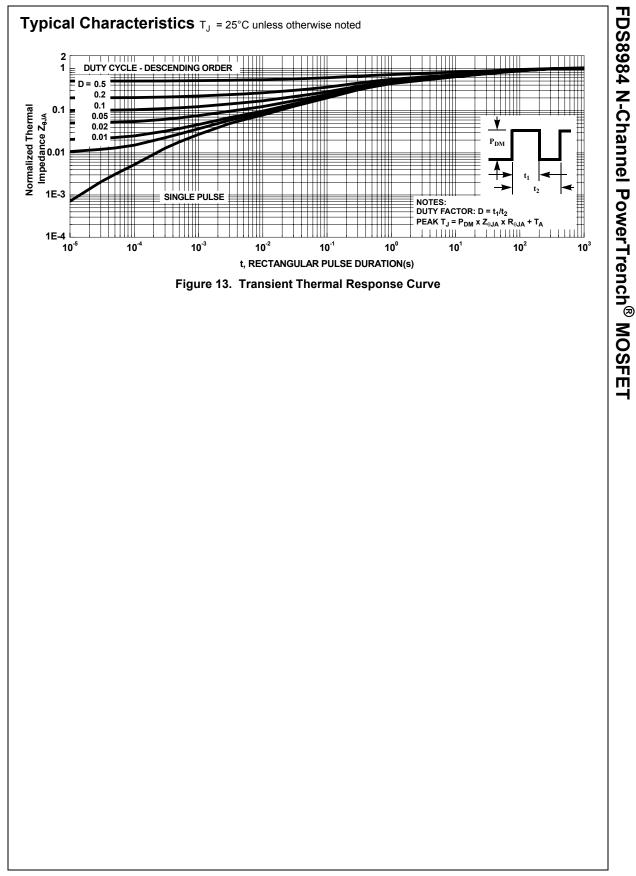


FDS8984 N-Channel PowerTrench<sup>®</sup> MOSFET

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